

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

13 G. Story

In re PATENT APPLICATION of

OKI.147

Kazuhiko Asakawa et al.

Group Art Unit: 2814

Serial No.: 09/497,499

Examiner: Louie, W

Filed: February 4, 2000

For:

SEMICONDUCTOR DEVICE AND METHODS OF FABRICATING THE SAME

## Response Under 37 CFR §1.111

Honorable Commissioner of 12/05/2002 GETANLEY 10000003-500238 03497499 of FC:1202 Washington, D.C. 20231

Sir:

In response to the Office Action of April 24, 2002, the following amendment and remarks are respectfully made. Concurrently, a Petition to Revive Under 37 CFR 1.137(b) is being submitted.

## In the Claims:

- 1. Please add the following claims:
- 19. (Newly Added) A semiconductor memory device, comprising:

a semiconductor substrate, which has a first region and a second region formed on a major surface thereof;

a first insulating layer, which is formed over the first region;

a dummy pattern, which has a predetermined shape, and which is formed on said first insulating layer;

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